

2SK0198 (2SK198)

Silicon N-Channel Junction FET

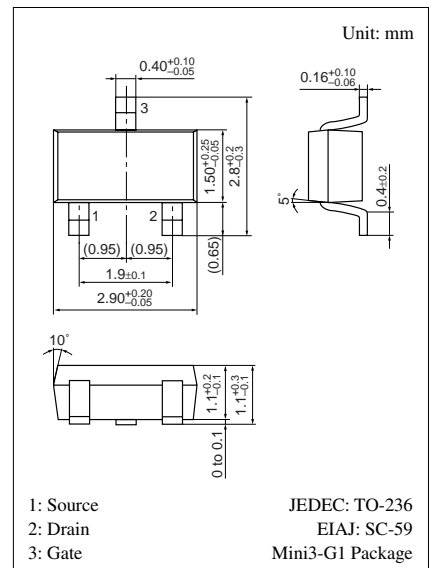
For low-frequency amplification

■ Features

- High mutual conductance g_m
- Low noise type
- Mini-type package, allowing downsizing of the sets and automatic insertion through the tape/magazine packing.

■ Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Rated | Unit |
|-----------------------------|-----------|-------------|------------------|
| Drain to Source voltage | V_{DSX} | 30 | V |
| Gate to Drain voltage | V_{GDO} | -30 | V |
| Drain current | I_D | 20 | mA |
| Gate current | I_G | 10 | mA |
| Allowable power dissipation | P_D | 150 | mW |
| Channel temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |



Marking Symbol (Example): 10

■ Electrical Characteristics ($T_a = 25^\circ\text{C}$)

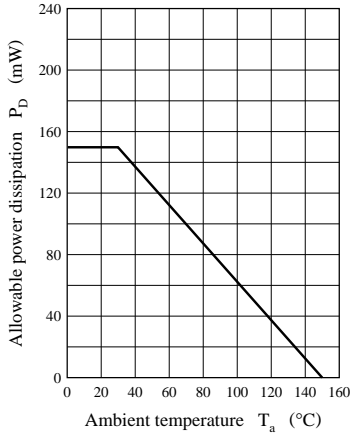
| Parameter | Symbol | Conditions | min | typ | max | Unit |
|--|-------------|--|------|-----|------|------|
| Drain to Source cut-off current | I_{DSS}^* | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | 0.5 | | 12 | mA |
| Gate to Source leakage current | I_{GSS} | $V_{GS} = -30\text{ V}, V_{DS} = 0$ | | | -100 | nA |
| Gate to Source cut-off voltage | V_{GSC} | $V_{DS} = 10\text{ V}, I_D = 10\ \mu\text{A}$ | -0.1 | | -1.5 | V |
| Mutual conductance | g_m | $V_{DS} = 10\text{ V}, I_D = 0.5\text{ mA}, f = 1\text{ kHz}$ | 4 | | | mS |
| | | $V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ kHz}$ | | 13 | | |
| Input capacitance (Common Source) | C_{iss} | $V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$ | | 14 | | pF |
| Reverse transfer capacitance (Common Source) | C_{rss} | | | 3.5 | | pF |
| Noise figure | NV | $V_{DS} = 30\text{ V}, I_D = 1\text{ mA}, G_v = 80\text{ dB}$ $R_g = 100\text{ k}\Omega, \text{Function} = \text{FLAT}$ | | 60 | | mV |

* I_{DSS} rank classification

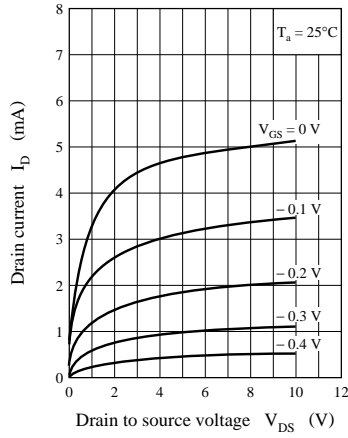
| Rank | P | Q | R |
|----------------|----------|--------|---------|
| I_{DSS} (mA) | 0.5 to 3 | 2 to 6 | 4 to 12 |
| Marking Symbol | 1OP | 1OQ | 1OR |

(Note) The part number in the parenthesis shows conventional part number.

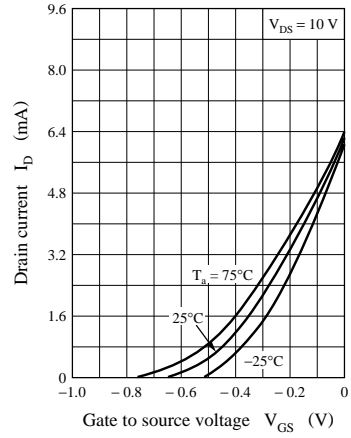
$P_D - T_a$



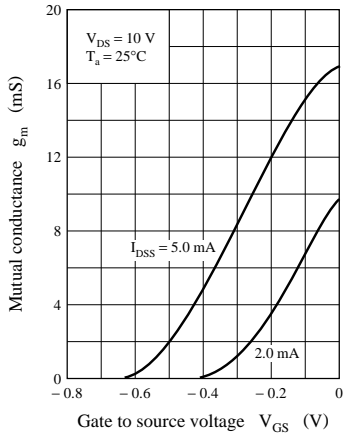
$I_D - V_{DS}$



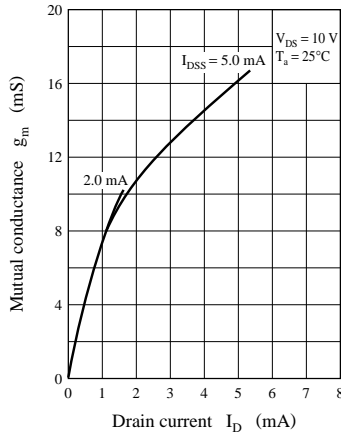
$I_D - V_{GS}$



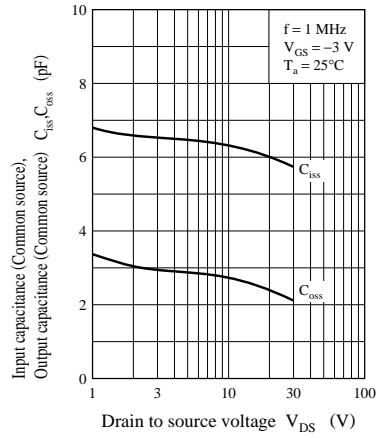
$g_m - V_{GS}$



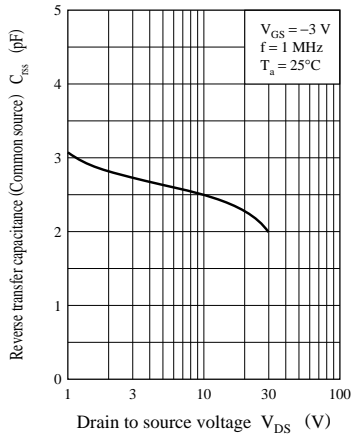
$g_m - I_D$



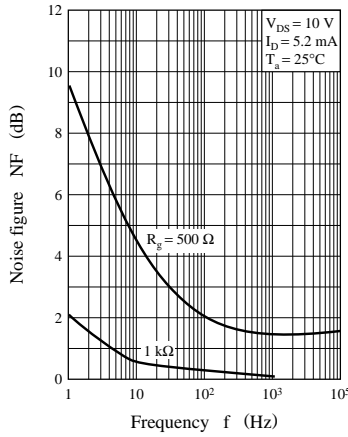
$C_{iss}, C_{oss} - V_{DS}$



$C_{rss} - V_{DS}$



NF — f



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